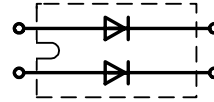


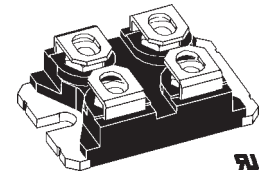
Power Schottky Rectifier

$I_{FAV} = 2x100 \text{ A}$
 $V_{RRM} = 200 \text{ V}$
 $V_F = 0.84 \text{ V}$

V_{RSM}	V_{RRM}	Type
V	V	
200	200	DSS 2x101-02A



miniBLOC,
SOT-227 B



Symbol	Conditions	Maximum Ratings	
I_{FRMS}		150	A
I_{FAVM}	$T_C = 105^\circ\text{C}$; rectangular, $d = 0.5$	100	A
I_{FAVM}	$T_C = 105^\circ\text{C}$; rectangular, $d = 0.5$; per device	200	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t_p = 10 \text{ ms}$ (50 Hz), sine	1400	A
E_{AS}	$I_{AS} = 4 \text{ A}$; $L = 100 \mu\text{H}$; $T_{VJ} = 25^\circ\text{C}$; non repetitive	0.8	mJ
I_{AR}	$V_A = 1.5 \cdot V_{RRM}$ typ.; $f = 10 \text{ kHz}$; repetitive	0.4	A
$(dv/dt)_{cr}$		18	kV/ μs
T_{VJ}		-40...+150	$^\circ\text{C}$
T_{VJM}		150	$^\circ\text{C}$
T_{stg}		-40...+150	$^\circ\text{C}$
P_{tot}	$T_C = 25^\circ\text{C}$	310	W
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	2500	V~
M_d	mounting torque (M4)	1.1-1.5/9-13	Nm/lb.in.
	terminal connection torque (M4)	1.1-1.5/9-13	Nm/lb.in.
Weight	typical	30	g

Features

- International standard package miniBLOC
- Isolation voltage 2500 V~
- UL registered E 72873
- 2 independent Schottky diodes in 1 package
- Very low V_F
- Extremely low switching losses
- Low I_{RM} -values

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Dimensions see [Outlines.pdf](#)

Symbol	Conditions	Characteristic Values	
		typ.	max.
I_R ①	$V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	4	mA
		10	mA
V_F	$I_F = 100 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$	0.84	V
	$I_F = 100 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	0.94	V
	$I_F = 200 \text{ A}$; $T_{VJ} = 125^\circ\text{C}$	1.11	V
R_{thJC}	per diode	0.4	K/W
R_{thCH}	per diode	0.1	K/W

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0%
Data according to IEC 60747 and per diode unless otherwise specified.

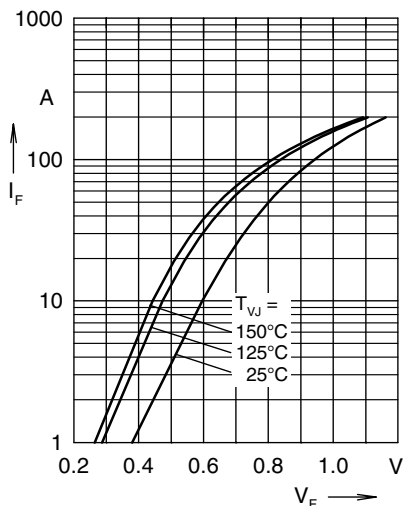


Fig. 1 Max. forward voltage drop characteristics

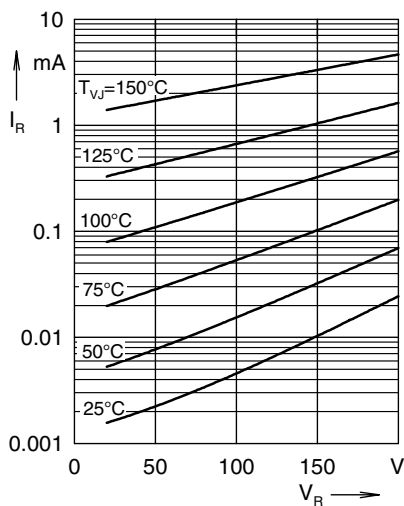


Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

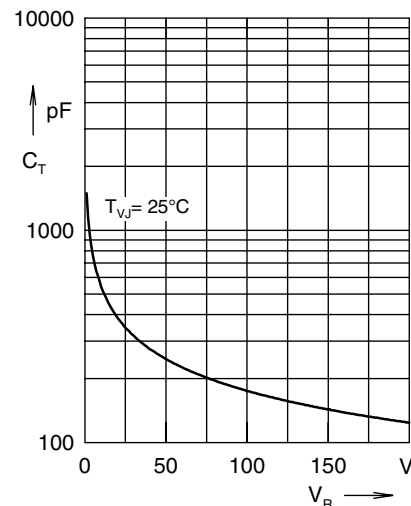


Fig. 3 Typ. junction capacitance C_T versus reverse voltage V_R

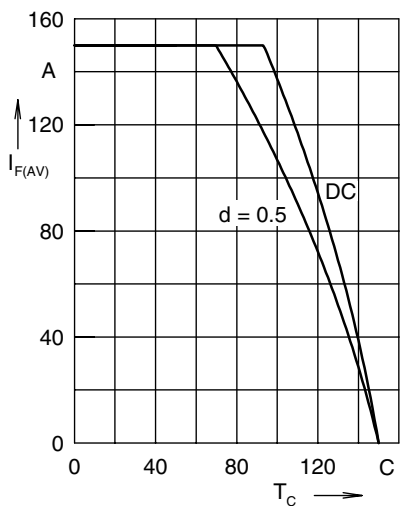


Fig. 4 Average forward current $I_{F(AV)}$ versus case temperature T_C

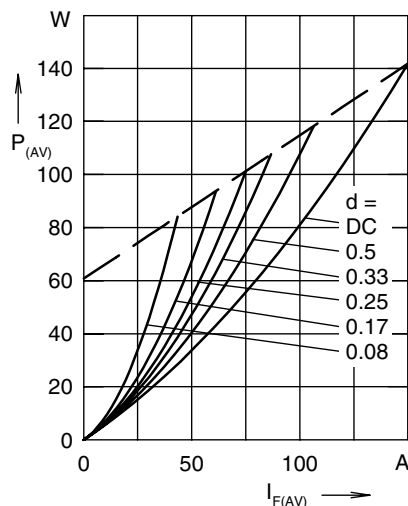


Fig. 5 Forward power loss characteristics

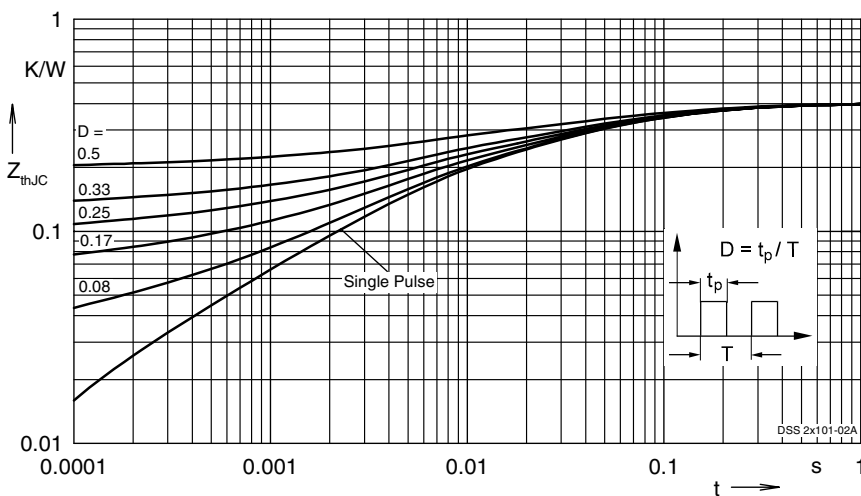


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode